MMBT6428LT1G, MMBT6429LT1G, NSVMMBT6429LT1G

Amplifier Transistors

NPN Silicon

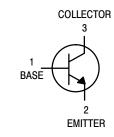
Features

- NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q101 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant



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| Rating | Symbol | 6428LT1 | 6429LT1 | Unit |
|--------------------------------|------------------|---------|---------|------|
| Collector-Emitter Voltage | V _{CEO} | 50 | 45 | Vdc |
| Collector-Base Voltage | V _{CBO} | 60 | 55 | Vdc |
| Emitter-Base Voltage | V _{EBO} | 6.0 | | Vdc |
| Collector Current – Continuous | Ι _C | 200 | | mAdc |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS

| Rating | Symbol | Value | Unit | |
|--|-----------------------------------|-------------|-------------|--|
| Total Device Dissipation FR-5 Board (Note 1) $T_A = 25^{\circ}C$ Derate above 25°C | P _D | 225 1.8 | mW mW/⁰C | |
| Derate above 25 C | | 1.0 | | |
| Thermal Resistance, Junction-to-Ambient | $R_{\theta JA}$ | 556 | °C/W | |
| Total Device Dissipation Alumina Substrate, (Note 2) $T_A = 25^{\circ}C$ | PD | 300 | mW | |
| Derate above 25°C | | 2.4 | mW/°C | |
| Thermal Resistance, Junction-to-Ambient | R_{\thetaJA} | 417 | °C/W | |
| Junction and Storage Temperature | T _J , T _{stg} | -55 to +150 | °C | |

1. FR-5 = $1.0 \times 0.75 \times 0.062$ in.

2. Alumina = 0.4 \times 0.3 \times 0.024 in. 99.5% alumina.



SOT-23 (TO-236) CASE 318 STYLE 6

MARKING DIAGRAM



XXX = Specific Device Code MMBT6428LT1 – 1KM

- NSV/MMBT6429LT1 M1L
- M = Date Code*
- = Pb–Free Package

(Note: Microdot may be in either location) *Date Code orientation and/or overbar may vary depending upon manufacturing location.

ORDERING INFORMATION

| Device | Package | Shipping [†] |
|-----------------|---------------------|-----------------------|
| MMBT6428LT1G | SOT-23 (Pb-Free) | 3000 Tape & Reel |
| MMBT6429LT1G | SOT–23 (Pb–Free) | 3000 Tape & Reel |
| NSVMMBT6429LT1G | SOT–23 (Pb–Free) | 3000 Tape & Reel |

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted)

| Characteris | tic | Symbol | Min | Max | Unit |
|---|------------------------------------|----------------------|----------|------|------|
| OFF CHARACTERISTICS | | | | | |
| Collector – Emitter Breakdown Voltage $(I_C = 1.0 \text{ mAdc}, I_B = 0)$ $(I_C = 1.0 \text{ mAdc}, I_B = 0)$ | MMBT6428 MMBT6429 / NSVMMBT6429 | V _{(BR)CEO} | 50 45 | | Vdc |
| Collector – Base Breakdown Voltage $(I_C = 0.1 \text{ mAdc}, I_E = 0)$ $(I_C = 0.1 \text{ mAdc}, I_E = 0)$ | MMBT6428 MMBT6429 / NSVMMBT6429 | V _{(BR)CBO} | 60 55 | | Vdc |
| Collector Cutoff Current (V _{CE} = 30 Vdc) | | ICES | - | 0.1 | μAdc |
| Collector Cutoff Current ($V_{CB} = 30 \text{ Vdc}, I_E = 0$) | | I _{CBO} | - | 0.01 | μAdc |
| Emitter Cutoff Current ($V_{EB} = 5.0 \text{ Vdc}, I_C = 0$) | | I _{EBO} | - | 0.01 | μAdc |

ON CHARACTERISTICS

| DC Current Gain | | h _{FE} | | | - |
|---|------------------------------------|----------------------|------------|-------------|-----|
| $(I_{C} = 0.01 \text{ mAdc}, V_{CE} = 5.0 \text{ Vdc})$ | MMBT6428 MMBT6429 / NSVMMBT6429 | | 250 500 | - | |
| $(I_{C} = 0.1 \text{ mAdc}, V_{CE} = 5.0 \text{ Vdc})$ | MMBT6428 MMBT6429 / NSVMMBT6429 | | 250 500 | 650 1250 | |
| $(I_{C} = 1.0 \text{ mAdc}, V_{CE} = 5.0 \text{ Vdc})$ | MMBT6428 MMBT6429 / NSVMMBT6429 | | 250 500 | - | |
| $(I_{C} = 10 \text{ mAdc}, V_{CE} = 5.0 \text{ Vdc})$ | MMBT6428 MMBT6429 / NSVMMBT6429 | | 250 500 | - | |
| Collector – Emitter Saturation Voltage ($I_C = 10 \text{ mAdc}, I_B = 0.5 \text{ mAdc}$) ($I_C = 100 \text{ mAdc}, I_B = 5.0 \text{ mAdc}$) | | V _{CE(sat)} | - | 0.2 0.6 | Vdc |
| Base-Emitter On Voltage (I _C = 1.0 mAdc, V _{CE} = 5.0 Vdc) | | V _{BE(on)} | 0.56 | 0.66 | Vdc |

SMALL-SIGNAL CHARACTERISTICS

| Current-Gain – Bandwidth Product ($I_C = 1.0 \text{ mAdc}, V_{CE} = 5.0 \text{ Vdc}, f = 100 \text{ MHz}$) | f _T | 100 | 700 | MHz |
|---|------------------|-----|-----|-----|
| Output Capacitance (V_{CB} = 10 Vdc, I _E = 0, f = 1.0 MHz) | C _{obo} | - | 3.0 | pF |
| Input Capacitance ($V_{EB} = 0.5 \text{ Vdc}, I_C = 0, f = 1.0 \text{ MHz}$) | C _{ibo} | - | 8.0 | pF |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

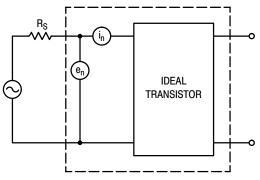


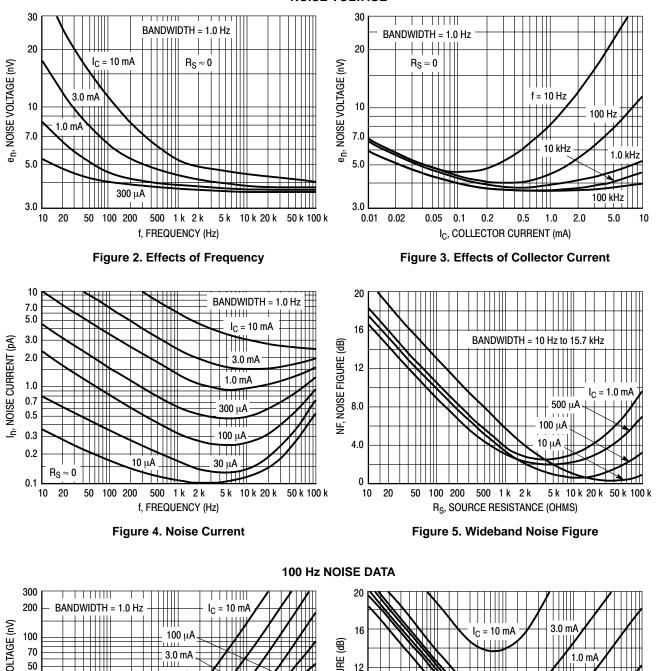
Figure 1. Transistor Noise Model

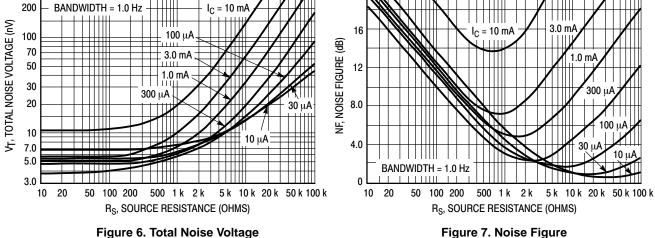
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NOISE CHARACTERISTICS

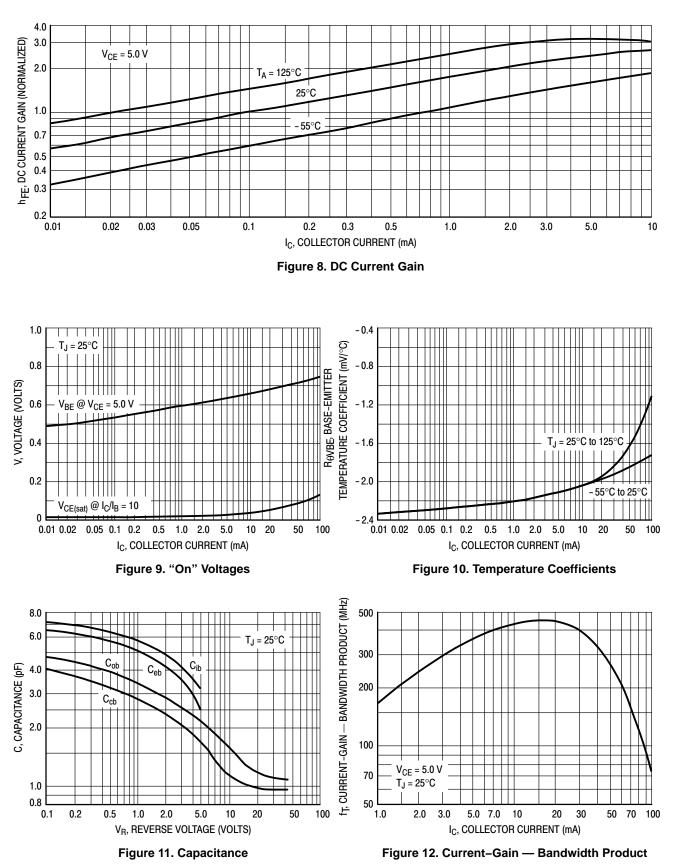
 $(V_{CE} = 5.0 \text{ Vdc}, T_A = 25^{\circ}C)$

NOISE VOLTAGE





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